

# MMST440<sup>2</sup>

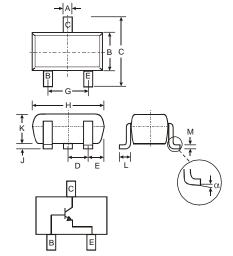
### NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

# **Features**

- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (MMST4403)
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

# **Mechanical Data**

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: K3X See Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.006 grams (approximate)



SOT-323											
Dim	Min	Max									
Α	0.25	0.40									
В	1.15	1.35									
С	2.00 2.20										
D	D 0.65 Nominal										
E	0.30	0.40									
G	1.20	1.40									
Н	1.80	2.20									
J	0.0	0.10									
K	0.90 1.00										
L	0.25 0.										
М	0.10	0.18 8°									
α	0°										
All Dimensions in mm											

# Maximum Ratings @TA = 25℃ unless otherwise specified

Characteristic	Symbol	Value	Unit		
Collector-Base Voltage	V <sub>CBO</sub>	60	V		
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V		
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V		
Collector Current – Continuous (Note 1)	Ic	600	mA		
Power Dissipation (Note 1)	Pd	200	mW		
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ hetaJA}$	625	°C/W		
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C		

Notes:

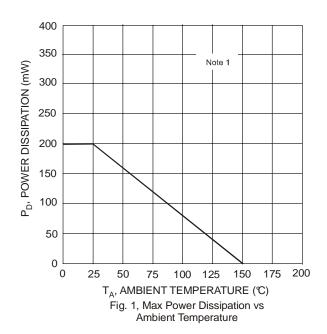
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

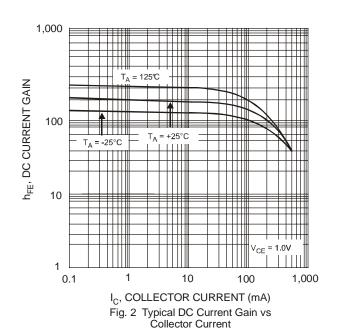


#### **Electrical Characteristics** @T<sub>A</sub> = 25℃ unless otherwise specified

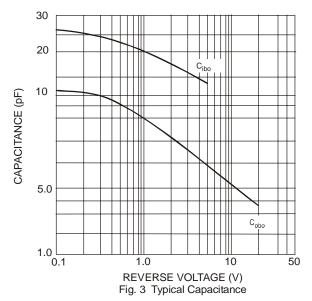
Characteristic	Symbol	Min	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 5)							
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	60	_	V	$I_C = 100 \mu A, I_E = 0$		
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	40	_	V	$I_C = 1.0 \text{mA}, I_B = 0$		
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6.0	_	V	$I_E = 100 \mu A, I_C = 0$		
Collector Cutoff Current	I <sub>CEX</sub>	_	100	nA	$V_{CE} = 35V$ , $V_{EB(OFF)} = 0.4V$		
Base Cutoff Current	I <sub>BL</sub>	_	100	nA	$V_{CE} = 35V$ , $V_{EB(OFF)} = 0.4V$		
ON CHARACTERISTICS (Note 5)	•		-				
		20	_		$I_C = 100 \mu A, V_{CE} = 1.0 V$		
		40	_		$I_C = 1.0 \text{mA}, V_{CE} = 1.0 \text{V}$		
DC Current Gain	hFE	80	_		$I_C = 10 \text{mA}, V_{CE} = 1.0 \text{V}$		
		100	300		$I_C = 150 \text{mA}, V_{CE} = 1.0 \text{V}$		
		40	_		$I_C = 500 \text{mA}, V_{CE} = 2.0 \text{V}$		
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.40	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$		
Concolor Emiliar Galaration Voltage	VCE(SAT)		0.75	•	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$		
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	0.75	0.95	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$		
, and the second	V BE(SAT)	_	1.2	,	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$		
SMALL SIGNAL CHARACTERISTICS	1	1	1	ı			
Output Capacitance	C <sub>ob</sub>	_	8.5	pF	$V_{CB} = 5.0V$ , $f = 1.0MHz$ , $I_E = 0$		
Input Capacitance	C <sub>eb</sub>	_	30	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$		
Input Impedance	h <sub>ie</sub>	1.0	15	kΩ			
Voltage Feedback Ratio	h <sub>re</sub>	0.1	8.0	x 10 <sup>-4</sup>	$V_{CE} = 10V, I_{C} = 1.0mA,$		
Small Signal Current Gain	h <sub>fe</sub>	40	500		f = 1.0MHz		
Output Admittance	h <sub>oe</sub>	1.0	30	μS			
Current Gain-Bandwith Product	f <sub>T</sub>	250	_	MHz	$V_{CE} = 10V, I_{C} = 20mA,$ f = 100MHz		
SWITCHING CHARACTERISTICS	•				-		
Delay Time	t <sub>d</sub>		15	ns	$V_{CC} = 30V, I_C = 150mA,$		
Rise Time	t <sub>r</sub>		20	ns	$V_{BE(OFF)} = 2.0V, I_{B1} = 15mA$		
Storage Time	t <sub>s</sub>	_	225	ns	$V_{CC} = 30V, I_C = 150mA,$		
Fall Time	t <sub>r</sub>	_	30	ns	$I_{B1} = I_{B2} = 15mA$		

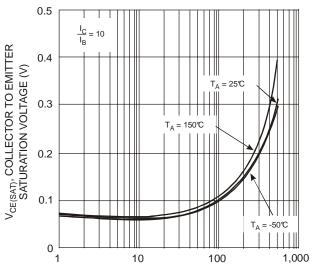
<sup>5.</sup> Short duration pulse test used to minimize self-heating effect.



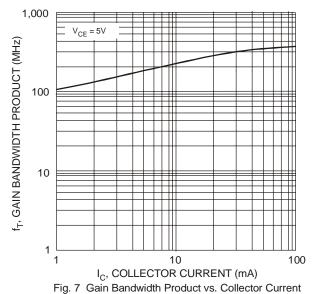


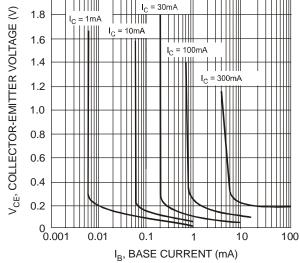






I<sub>C</sub>, COLLECTOR CURRENT (mA)
Fig. 5 Collector Emitter Saturation Voltage
vs. Collector Current





2.0

Fig. 4 Typical Collector Saturation Region

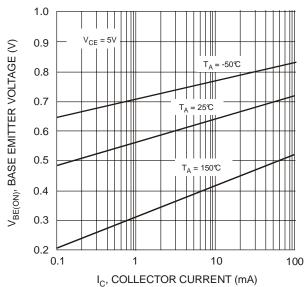


Fig. 6 Base Emitter Voltage vs. Collector Current

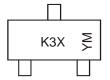


#### **Ordering Information** (Note 4 & 6)

Device	Packaging	Shipping			
MMST4401-7-F	SOT-323	3000/Tape & Reel			

6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:

# **Marking Information**



K3X = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002

M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Χ	Υ	Z
Month	Jan	Fel	b	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Oc	t	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		N	D

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